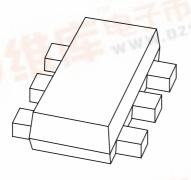
DISCRETE SEMICONDUCTORS

DATA SHEET



PEMB1

PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

Preliminary specification

2001 Sep 13







PEMB1

FEATURES

- 300 mW total power dissipation
- Very small 1.6 mm x 1.2 mm ultra thin package
- Excellent coplanarity due to straight leads
- Replaces two SC-75/SC-89 packaged transistors on same PCB area
- Reduces required PCB area
- Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- · Circuit driver.

DESCRIPTION

PNP resistor-equipped transistors in a SOT666 plastic package.

MARKING

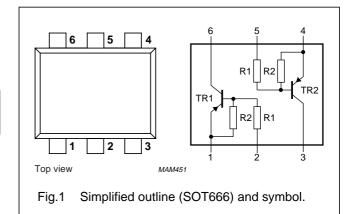
TYPE NUMBER	MARKING CODE
PEMB1	Z4

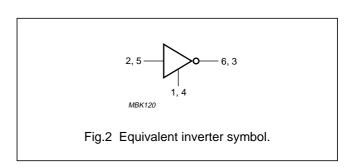
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-50	V
I _{CM}	peak collector current	-100	mA
TR1	PNP	_	_
TR2	PNP	_	_
R1	bias resistor	22	kΩ
R2	bias resistor	22	kΩ

PINNING

PIN		DESCRIPTION
1, 4	emitter	TR1; TR2
2, 5	base	TR1; TR2
6, 3	collector	TR1; TR2





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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT		
Per transistor unless otherwise specified							
V _{CBO}	collector-base voltage	open emitter	_	-50	V		
V_{CEO}	collector-emitter voltage	open base	-	-50	V		
V _{EBO}	emitter-base voltage	open collector	-	-10	V		
VI	input voltage						
	positive		_	+12	V		
	negative		_	-5	V		
I _O	output current (DC)		_	-100	mA		
I _{CM}	peak collector current		_	-100	mA		
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	-	200	mW		
T _{stg}	storage temperature		-65	+150	°C		
Tj	junction temperature		_	150	°C		
T _{amb}	operating ambient temperature		-65	+150	°C		
Per device)						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	300	mW		

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	notes 1 and 2	416	K/W

Notes

- 1. Transistor mounted on an FR4 printed-circuit board.
- 2. The only recommended soldering method is reflow soldering.

^{1.} Transistor mounted on a FR4 printed-circuit board.

PEMB1

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

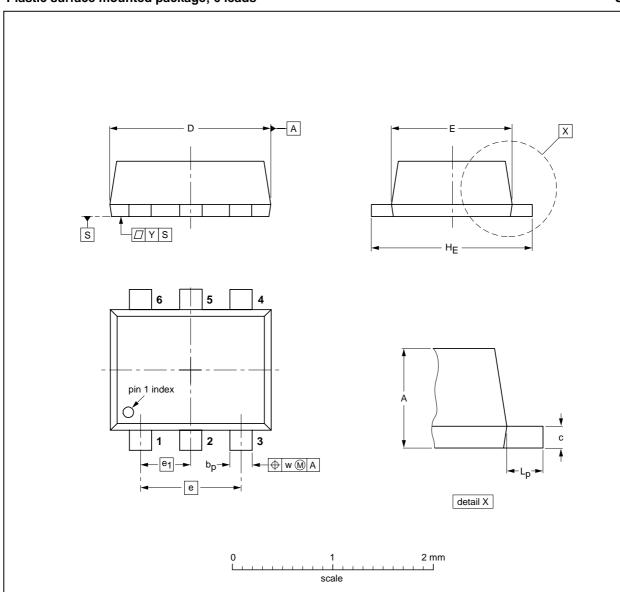
SYMBOL	PARAMETER	PARAMETER CONDITIONS		TYP.	MAX.	UNIT	
Per transis	Per transistor unless otherwise specified						
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_{C} = 0$	_	_	-100	nA	
I _{CEO}	collector-emitter cut-off current	$V_{CE} = -50 \text{ V}; I_{B} = 0$	_	_	-1	μΑ	
		$V_{CE} = -30 \text{ V}; I_{B} = 0; T_{j} = 150 ^{\circ}\text{C}$	_	_	-50	μΑ	
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0$	_	_	-180	μΑ	
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$	60	_	_		
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$	_	_	-150	mV	
V _{i(off)}	input off voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	_	-1.1	-0.8	V	
V _{i(on)}	input on voltage	$V_{CE} = -0.3 \text{ V}; I_{C} = -10 \text{ mA}$	-2.5	-1.7	_	V	
R1	input resistor		15.4	22	28.6	kΩ	
R2 R1	resistor ratio		0.8	1	1.2	kΩ	
C _c	collector capacitance	$I_E = I_e = 0$; $V_{CB} = -10 \text{ V}$; $f = 1 \text{ MHz}$	-	_	3	pF	

PEMB1

PACKAGE OUTLINE

Plastic surface mounted package; 6 leads

SOT666



DIMENSIONS (mm are the original dimensions)

UNIT	Α	bp	С	D	E	е	e ₁	HE	Lp	w	у
mm	0.6 0.5	0.27 0.17	0.18 0.08	1.7 1.5	1.3 1.1	1.0	0.5	1.7 1.5	0.3 0.1	0.1	0.1

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT666						-01-01-04 01-08-27

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DATA SHEET STATUS

DATA SHEET STATUS(1)	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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